

	Type	Hits	Search Text	DBs	Time Stamp	Comm en ts	Er ro r De f i n i t i o n	Er ro rs	Ref #
1	IS& R	2	("20030194496").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/14 19:17				S1
2	IS& R	2	("6668752").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/12 13:40				S2
3	IS& R	2	("20040067308").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 01:15				S3
4	IS& R	2	("20030049388").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/12 13:42				S4
5	IS& R	2	("6436824").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/12 13:42				S5
6	BRS	4	(silicon adj carbide or sic) with (plasma near cvd pecvd) and silicon and hydrogen and carbon and inert adj gas and (cure\$6 or curi\$6 or curab\$6) with (silicon adj carbide or sic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:14				S6

7	BRS	4	(cure\$6 or curi\$6 or curab\$6) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:17				S7
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8	BRS	109	(cure\$6 or heat\$5 or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 23:49			S8
9	BRS	1	(cure\$6 or heat\$5 or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) with dielectric near constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:20			S9
10	BRS	0	(heat\$5 or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) same dielectric near constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:20			S10

11	BRS	7	(cure\$6 or heat\$5 or anneal\$4) same (silicon adj carbide or sic) same (rf or radio adj frequenc\$) same dielectric near constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:21				S11
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12	BRS	11	(cure\$6 or heat\$5 or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) and dielectric adj constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:33				S12
13	BRS	18	(silicon adj carbide or sic) with (rf or radio adj frequenc\$) with dielectric adj constant	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/11/15 03:34				S13
14	IS& R	2	("6635941").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/14 19:19				S15
15	BRS	9	(cure\$6 or heat\$5 or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) and sic adj h	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 18:17				S17

	Type	Hits	Search Text	DBs	Time Stamp	Com m m e n t s	Er r o r D e f i n i t i o n	Er r o r s	Ref #
16	BRS	47	(cure\$6 or heat\$5 or anneal\$4) and (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and sic adj h and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 18:18				S19
17	BRS	18	(cure\$6 or heat\$5 or anneal\$4) with (rf or radio adj frequenc\$4) and (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and sic adj h and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 18:58				S20

	Type	Hits	Search Text	DBs	Time Stamp	Corr mmDe enfi tsni tion	Er ro rs	Ref #
18	BRS	18	(cure\$6 or heat\$5 or anneal\$4) with (rf or radio adj frequenc\$4) and (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and (sic adj h or hydrogen near doped near silicon near carbide) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 18:59			S21
19	BRS	47	(cure\$6 or heat\$5 or anneal\$4) and (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and (sic adj h or hydrogen near doped near silicon near carbide) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 22:27			S22

	Type	Hits	Search Text	DBs	Time Stamp	Corr mmen ts	Defi niti on	Er ro rs	Ref #
20	BRS	47	(cure\$6 or heat\$5 or anneal\$4) and (rf or radio adj frequenc\$) and (sic adj h or hydrogen near doped near silicon near carbide) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 22:27				S23
21	BRS	18	(cure\$6 or heat\$5 or anneal\$4) with (rf or radio adj frequenc\$) and (sic adj h or hydrogen near doped near silicon near carbide) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 23:10				S24
22	BRS	39	sicoh with sich	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 23:11				S25
23	BRS	16	sicoh with sich and (rf or radio adj frequency)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/20 23:12				S27
24	IS& R	2	("6312793").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 01:16				S28



25	IS& R	2	("6147009").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 01:16				S29
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26	BRS	1	cure\$6 with (silicon adj carbide or sic or hydrogen\$6 near silicon near carbide or sich or sicoh) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 23:52				S30
27	BRS	3	(cure\$6 or anneal\$4) with (silicon adj carbide or sic or hydrogen\$6 near silicon near carbide or sich or sicoh) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/21 23:53				S31

28	BRS	53	(cure\$6 or heat\$5 or anneal\$4) with (rf or radio adj frequenc\$4) and (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and (sic adj h or hydrogen\$6 near silicon near carbide) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 00:19				S32
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29	BRS	60	cur\$6 with (silicon adj carbide or sic) and (rf or radio adj frequenc\$) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 00:20				S33
30	BRS	15	cur\$6 with (silicon adj carbide or sic) and (rf or radio adj frequenc\$) with \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 00:56				S34
31	BRS	5	(cure or curing or cured) with (silicon adj carbide or sic) and (rf or radio adj frequenc\$) with \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 01:07				S35
32	BRS	2	(cure or curing or cured) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 00:58				S36

33	BRS	4	(cure or curing or cured) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 01:08				S37
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34	BRS	2	(cure or curing or cured or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$) and \$9ethylsilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 01:09				S39
35	BRS	6	(cure or curing or cured or anneal\$4) with (silicon adj carbide or sic) with (rf or radio adj frequenc\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/22 01:09				S40